

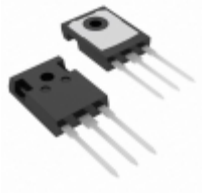
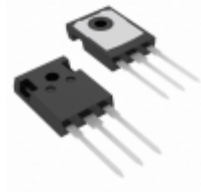
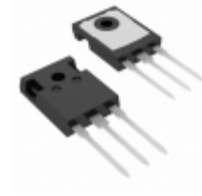



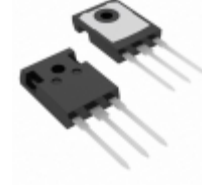

	FDH038AN08A1	
	Hersteller-Teilenummer:	FDH038AN08A1
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 75V 80A TO-247
	Datenblätter:	 FDH038AN08A1.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 30934 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FDH038AN08A1
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 75V 80A TO-247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	30934 pcs Stock
detaillierte Beschreibung	N-Channel 75V 22A (Ta), 80A (Tc) 450W (Tc) Through
Serie	PowerTrench®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Verlustleistung (max)	450W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	75V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	22A (Ta), 80A (Tc)
Rds On (Max) @ Id, Vgs	3.8 mOhm @ 80A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	160nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	8665pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FDH038AN08A1 ist neu im Original, Suche FDH038AN08A1 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDH038AN08A1 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FDH038AN08A1: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDH055N15A Fairchild/ON Semiconductor MOSFET N-CH 150V TO-247-3</p>	 <p>FDH038AN08A1 Fairchild/ON Semiconductor MOSFET N-CH 75V 80A TO-247</p>	 <p>FDH15N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 15A TO-247</p>	 <p>FDH210AN08 FAIRCHILD FDH210AN08 FAIRCHILD</p>
 <p>FDH1040B-R14M=P3 TOKO TOKO SMD</p>	 <p>FDH055N15A AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V TO-247-3</p>	 <p>FDH047AN08AO Fairchild/ON Semiconductor MOSFET N-CH 75V 80A TO-247</p>	 <p>FDH047AN08AO FSC FDH047AN08AO FSC</p>

heiße Teile

Mehr

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FDH038AN08A1	FDH047AN08A0	FDH047AN08A0	FDH047AN08A0	FDH055N15A
D FDH055N15A	FDH15N50	FDH15N50	FDH210AN08	FDH210N08
FDH210N08	FDH27N50	FDH27N50	FDH300A.TR	FDH3369C
FDH44N50	FDH44N50	D FDH45N50F	FDH50N50	FDH50N50
FDH50N50_F133	D FDH5500_F085	FGPF4533RDTU	G6RN-1-24V	HUFA76619D3ST
IS34C02B-2ZLI	KA78L05AZ	LPV321M7	LT1175IS8#TRPBF	N630CH30
P569F2101	PC817X3CSP9F	SI1417EDH-T1-GE3	D SI4532ADY-TI-E3	SSM3K38MFV
STW4810CHDT/LF	T2035H-600TRG	TPS62291DRVR	TS3L500RHURG4	XC6221A181MR

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